## NSN 5961-01-096-1892



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-096-1892 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches **Terminal Length:** 0.312 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Terminal and unthreaded hole **Terminal Circle Diameter:** 0.430 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 200.00 milliamperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a

No

**Unit Of Measure:** 

Demilitarization:

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